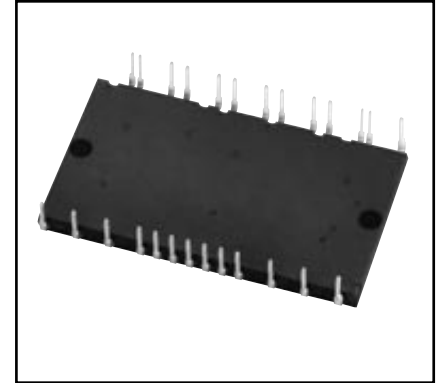
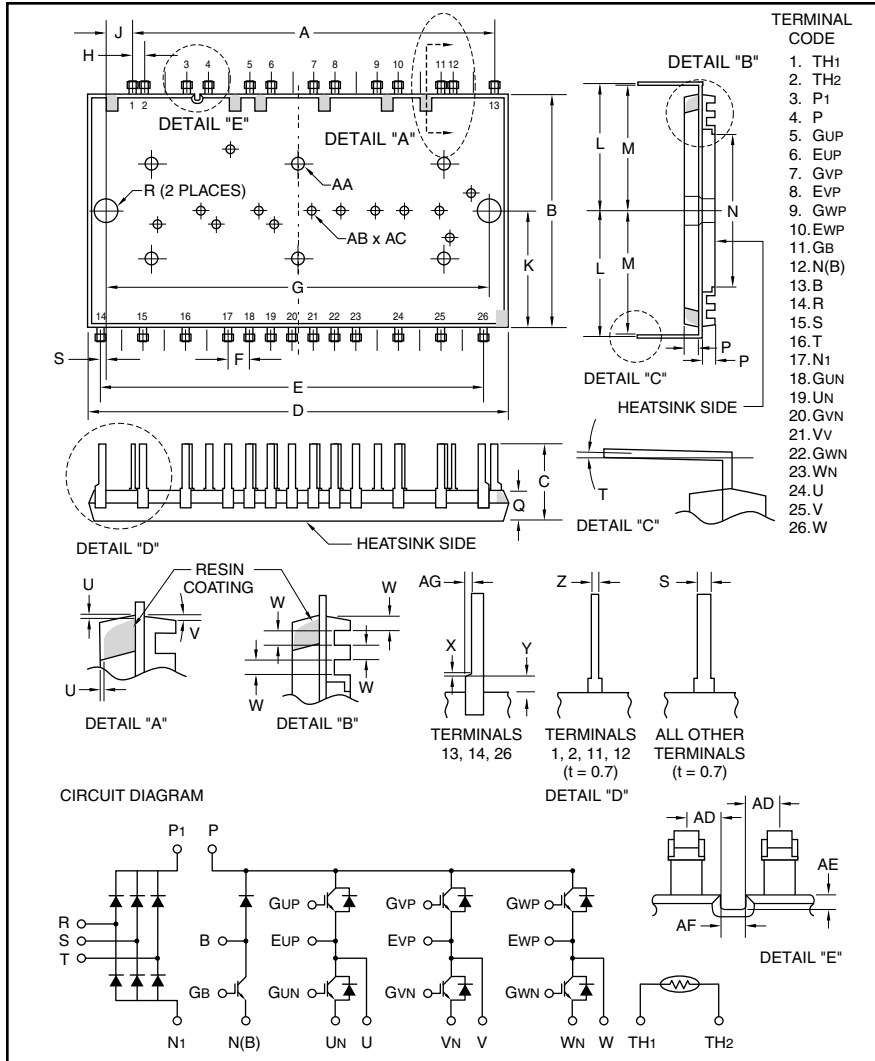


DIP-CIB

3Ø Converter + 3Ø Inverter + Brake
10 Amperes/1200 Volts



Description:

DIP-CIBs are low profile, thermally efficient, transfer mold modules. Each module consists of a three-phase diode converter section, a three-phase inverter section and a brake circuit. Open emitters allow the designer to sense the current in each phase leg for accurate and low cost current sensing. A thermistor is included in the package for sensing the base-plate temperature. 5th Generation CSTBT chips yield low loss. The module is completely Pb-Free and hence RoHS compliant.

Features:

- Compact Package
- Only 5.7mm Thick
- One Package for Entire Family
- Thermistor
- Open Emitters

Applications:

- AC Motor Control
- Servo Motors
- Robotics
- HVAC Inverters

Ordering Information:

CP10TD1-24A is a 1200 Volt, 10 Ampere DIP-CIB module.

Outline Drawing and Circuit Diagram

Dimensions	Inches	Millimeters
A	2.68	68.0
B	1.73	44.0
C	0.58±0.02	14.7±0.5
D	3.1	79.0
E	2.83	72.0
F	0.16±0.01	4.0±0.3
G	2.83±0.01	72.0±0.3
H	0.08±0.01	2.0±0.3
J	0.2±0.008	5.0±0.2
K	0.87	22.0
L	0.96±0.01	24.3±0.3
M	0.94±0.02	23.9±0.5
N	1.14	29.0
P	0.098	2.5
Q	0.22±0.02	5.7±0.5
R	0.18	4.5

Dimensions	Inches	Millimeters
S	0.04±0.008	1.0±0.2
T	0-5°	0-5°
U	0 Min.	0 Min.
V	8°	8°
W	0.04	1.1
X	0.02 Max.	0.5 Max.
Y	0.06	1.6
Z	0.023±0.008	0.6±0.2
AA	0.08 Dia.	2.0 Dia.
AB	0.1 Dia.	2.5 Dia.
AC	0.03 Deep	0.8 Deep
AD	0.057	1.45
AE	0.023	0.6
AF	0.04	1.1
AG	0.02±0.008	0.5±0.2

CP10TD1-24A

DIP-CIB

3Ø Converter + 3Ø Inverter + Brake

10 Amperes/1200 Volts

Absolute Maximum Ratings, $T_j = 25\text{ °C}$ unless otherwise specified

Ratings	Symbol	CP10TD1-24A	Units
Junction Temperature	T_j	-20 to 150	°C
Storage Temperature	T_{stg}	-40 to 125	°C
Mounting Torque, M4 Mounting Screws	—	13	in-lb
Module Weight Typical	—	52	Grams
Isolation Voltage (60Hz, Sinusoidal, AC 1 Min., Applied Between Pins and Heatsink)	V_{ISO}	2500	Volts

Inverter Part

Collector-Emitter Voltage (G-E Short)	V_{CES}	1200	Volts
Gate-Emitter Voltage (C-E Short)	V_{GES}	±20	Volts
Collector Current* (DC, $T_C = 100\text{ °C}$)	I_C	10	Amperes
Peak Collector Current** (Pulse)	I_{CM}	20	Amperes
Maximum Collector Dissipation ($T_C = 25\text{ °C}$)	P_C	96	Watts
Emitter Current* (DC, $T_C = 56\text{ °C}$)	I_E^{***}	10	Amperes
Peak Emitter Current** (Pulse)	I_{EM}^{***}	20	Amperes

Brake Part

Collector-Emitter Voltage (G-E Short)	V_{CES}	1200	Volts
Gate-Emitter Voltage (C-E Short)	V_{GES}	±20	Volts
Collector Current* (DC, $T_C = 100\text{ °C}$)	I_C	10	Amperes
Peak Collector Current** (Pulse)	I_{CM}	20	Amperes
Maximum Collector Dissipation ($T_C = 25\text{ °C}$, $T_j < 150\text{ °C}$)	P_C	104	Watts
Repetitive Peak Reverse Voltage (Clamp Diode Part)	V_{RRM}	1200	Volts
Forward Current (Clamp Diode Part, $T_j < 150\text{ °C}$)	I_{FM}	10	Amperes

Converter Part

Repetitive Peak Reverse Voltage	V_{RRM}	1600	Volts
Recommended AC Input Voltage	E_a	440	Volts
DC Output Current (Three-phase Rectifying Circuit)	I_O	10	Amperes
Surge Forward Current (1/2 Cycle at 60 Hz, Peak Value, Non-repetitive)	I_{FSM}	200	Amperes
I^2t for Fusing (Value for 1 Cycle of Surge Current)	I^2t	168	A^2s

* T_C is measured just underneath the power chip.

**Pulse width and repetition rate should be such that the device junction temperature (T_j) does not exceed $T_{j(max)}$ rating.

*** I_E , V_{EC} , t_{rr} , and Q_{rr} represent characteristics of the anti-parallelled emitter-to-collector free-wheel diode (FWDI).

CP10TD1-24A

DIP-CIB

3Ø Converter + 3Ø Inverter + Brake

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Electrical Characteristics, $T_j = 25\text{ }^\circ\text{C}$ unless otherwise specified

Characteristics	Symbol	Test Conditions	Min.	Typ.	Max.	Units
Inverter Part						
Collector-Cutoff Current	I_{CES}	$V_{CE} = V_{CES}, V_{GE} = 0V$	—	—	1.0	mA
Gate-Emitter Threshold Voltage	$V_{GE(th)}$	$I_C = 1.0mA, V_{CE} = 10V$	6.5	7.5	8.5	Volts
Gate-Emitter Cutoff Current	I_{GES}	$V_{GE} = 20V, V_{CE} = 0V$	—	—	1.0	μA
Collector-Emitter	$V_{CE(sat)}$	$I_C = 10A, V_{GE} = 15V, T_j = 25^\circ C$	—	1.8	2.5	Volts
Saturation Voltage*		$I_C = 10A, V_{GE} = 15V, T_j = 125^\circ C$	—	2.0	—	Volts
Input Capacitance	C_{ies}		—	—	2.04	nF
Output Capacitance	C_{oes}	$V_{CE} = 25V, V_{GE} = 0V, f = 1MHz$	—	—	0.16	nF
Reverse Transfer Capacitance	C_{res}		—	—	0.04	nF
Total Gate Charge	Q_G	$V_{CC} = 600V, I_C = 10A, V_{GE} = 15V$	—	57	—	nC
Turn-on Delay Time	$t_{d(on)}$		—	—	100	ns
Turn-on Rise Time	t_r	$V_{CC} = 600V, I_C = 10A,$	—	—	75	ns
Turn-off Delay Time	$t_{d(off)}$	$V_{GE} = \pm 15V, R_G = 33\Omega,$	—	—	300	ns
Turn-off Fall Time	t_f	$T_j = 25^\circ C,$	—	—	400	ns
Reverse Recovery Time**	t_{rr}	Inductive Load	—	200	—	ns
Reverse Recovery Charge**	Q_{rr}		—	0.3	—	μC
Emitter-Collector Voltage**	V_{EC}	$I_E = 10A, V_{GE} = 0V$	—	2.7	3.5	Volts
External Gate Resistance	R_G	—	33	—	330	Ω

Brake Part

Collector-Cutoff Current	I_{CES}	$V_{CE} = V_{CES}, V_{GE} = 0V$	—	—	1.0	mA
Gate-Emitter Threshold Voltage	$V_{GE(th)}$	$I_C = 1.0mA, V_{CE} = 10V$	6.5	7.5	8.5	Volts
Gate-Emitter Cutoff Current	I_{GES}	$V_{GE} = 20V, V_{CE} = 0V$	—	—	1.0	μA
Collector-Emitter	$V_{CE(sat)}$	$I_C = 10A, V_{GE} = 15V, T_j = 25^\circ C$	—	1.8	2.5	Volts
Saturation Voltage*		$I_C = 10A, V_{GE} = 15V, T_j = 125^\circ C$	—	2.0	—	Volts
Input Capacitance	C_{ies}		—	—	2.16	nF
Output Capacitance	C_{oes}	$V_{CE} = 10V, V_{GE} = 0V, f = 1MHz$	—	—	0.15	nF
Reverse Transfer Capacitance	C_{res}		—	—	0.04	nF
Total Gate Charge	Q_G	$V_{CC} = 600V, I_C = 10A, V_{GE} = 15V$	—	57	—	nC
Turn-on Delay Time	$t_{d(on)}$		—	—	100	ns
Turn-on Rise Time	t_r	$V_{CC} = 600V, I_C = 10A,$	—	—	75	ns
Turn-off Delay Time	$t_{d(off)}$	$V_{GE} = \pm 15V, R_G = 33\Omega,$	—	—	300	ns
Turn-off Fall Time	t_f	$T_j = 25^\circ C,$	—	—	400	ns
Reverse Recovery Time	t_{rr}	Inductive Load	—	200	—	ns
Reverse Recovery Charge	Q_{rr}		—	0.3	—	μC
Forward Voltage Drop	V_{FM}	$I_F = 10A, \text{Clamp Diode Part}$	—	2.7	3.5	Volts
External Gate Resistance	R_G	—	33	—	330	Ω

*Pulse width and repetition rate should be such as to cause negligible temperature rise.

** T_C is measured just underneath the power chip.

CP10TD1-24A
DIP-CIB
3Ø Converter + 3Ø Inverter + Brake
10 Amperes/1200 Volts

Electrical Characteristics, $T_j = 25\text{ °C}$ unless otherwise specified

Characteristics	Symbol	Test Conditions	Min.	Typ.	Max.	Units
Converter Part						
Repetitive Reverse Current	I_{RRM}	$V_R = V_{RRM}, T_j = 125\text{ °C}$	—	—	1.0	mA
Forward Voltage Drop	V_{FM}	$I_F = 10\text{ A}$	—	1.1	1.4	Volts

Thermal and Mechanical Characteristics, $T_j = 25\text{ °C}$ unless otherwise specified

Characteristics	Symbol	Test Conditions	Min.	Typ.	Max.	Units
Common Rating						
Contact Thermal Resistance	$R_{th(c-f)}$	Case-to-Fin, Thermal Grease Applied	—	0.047	—	°C/W

Inverter Part

Thermal Resistance, Junction to Case	$R_{th(j-c)Q}$	IGBT Part, Per 1/6 Module	—	—	1.4	°C/W
Thermal Resistance, Junction to Case	$R_{th(j-c)D}$	FWDi Part, Per 1/6 Module	—	—	2.0	°C/W

Brake Part

Thermal Resistance, Junction to Case	$R_{th(j-c)Q}$	IGBT Part	—	—	1.4	°C/W
Thermal Resistance, Junction to Case	$R_{th(j-c)D}$	FWDi Part	—	—	1.7	°C/W

Converter Part

Thermal Resistance, Junction to Case	$R_{th(j-c)}$	Per 1/6 Module	—	—	1.3	°C/W
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NTC Thermistor Part

Resistance	R_{th}	$T_C = 25\text{ °C}$	9.5	10.0	10.5	kΩ
B Constant*	$B(25/100)$	Resistance at 25°C, 100°C	—	3450	—	K

*Thermistor resistance R_X at arbitrary temperature $T_X(K)$ can be calculated with the B constant formula

$$R_X = R_{25} \cdot \exp\left[B(25/100) \cdot \left(\frac{1}{T_X} - \frac{1}{T_{25}}\right)\right]$$

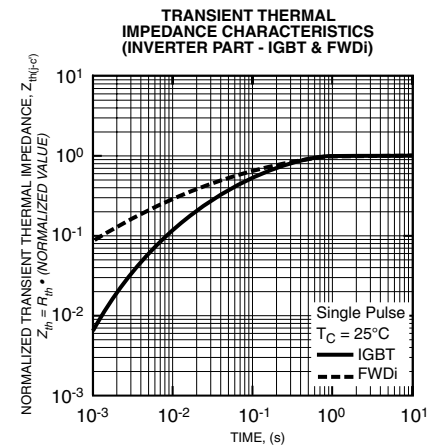
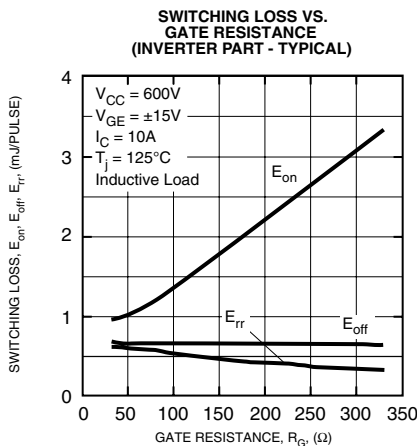
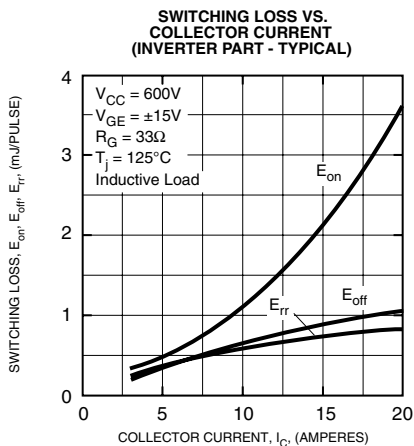
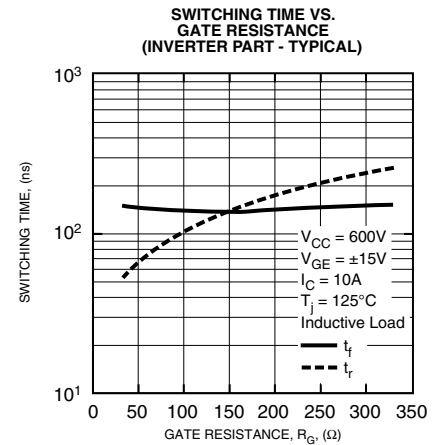
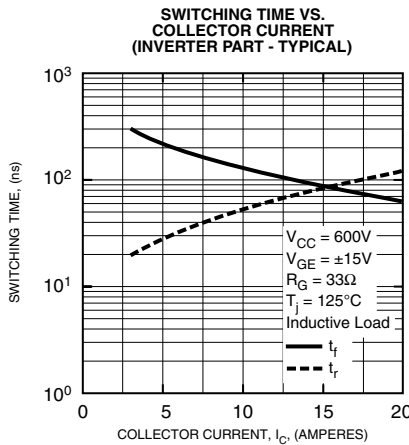
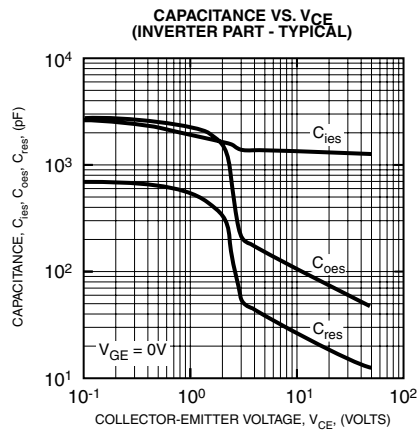
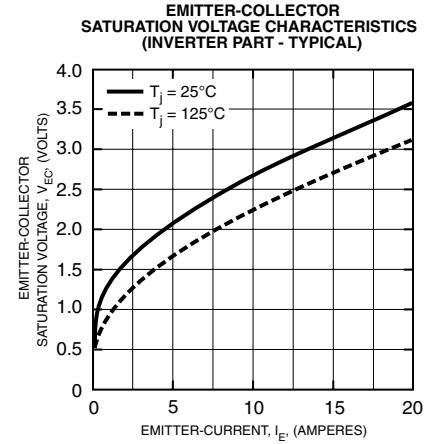
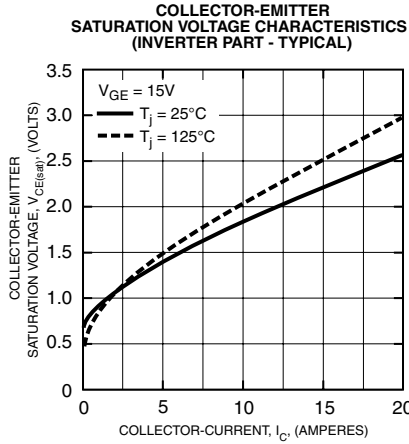
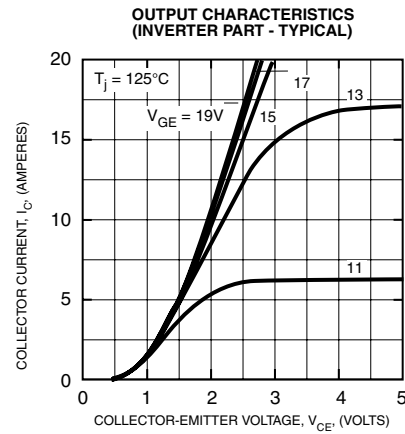
where R_{25} is the resistance at $T_C = 25\text{ °C}$, $T_{25} = 298\text{ K}$.

CP10TD1-24A

DIP-CIB

3Ø Converter + 3Ø Inverter + Brake

10 Amperes/1200 Volts



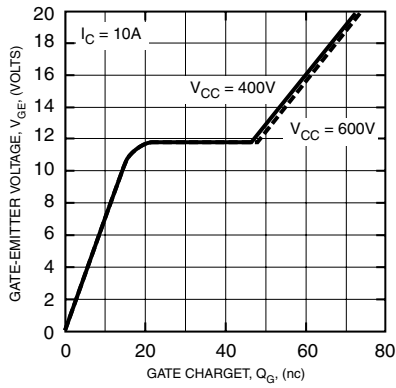
CP10TD1-24A

DIP-CIB

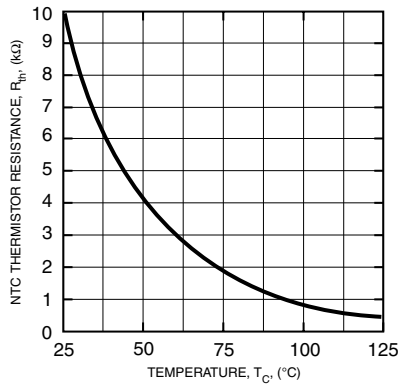
3Ø Converter + 3Ø Inverter + Brake

10 Amperes/1200 Volts

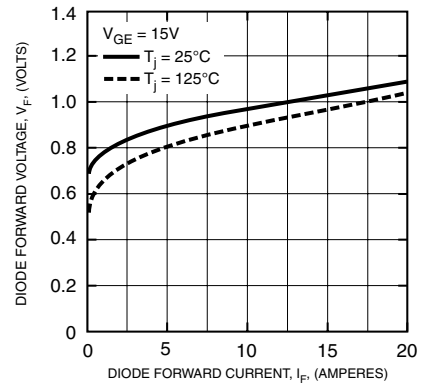
**GATE CHARGE
(INVERTER PART - TYPICAL)**



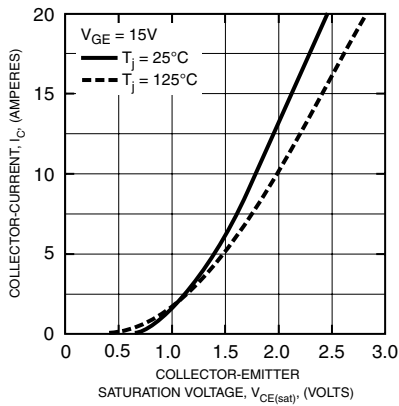
**NTC THERMISTOR
TEMPERATURE CHARACTERISTICS
(TYPICAL)**



**DIODE FORWARD
VOLTAGE CHARACTERISTICS
(CONVERTER PART - TYPICAL)**



**COLLECTOR-EMITTER
SATURATION VOLTAGE CHARACTERISTICS
(BRAKE PART - TYPICAL)**



**EMITTER-COLLECTOR
SATURATION VOLTAGE CHARACTERISTICS
(BRAKE PART - TYPICAL)**

